

Tunneling-induced high efficiency four-wave mixing in an asymmetric quantum wells

Hui Sun¹, Shuangli Fan^{1,*}, Hongjun Zhang¹, and Shangqing Gong^{2†}

¹*School of Physics and Information Technology, Shaanxi Normal University, Xi'an 710062, China*

²*Department of Physics, East China University of Science and Technology, Shanghai 200237, China*

(Dated: September 14, 2018)

An asymmetric double quantum wells (QWs) structure with resonant tunneling is suggested to achieve high efficient four wave mixing (FWM). We analytically demonstrate that the resonant tunneling can induce high efficient mixing wave in such a semiconductor structure with a low light pump wave. In particular, the FWM conversion efficiency can be enhanced dramatically in the vicinity of the center frequency. This interesting scheme may be used to generate coherent long-wavelength radiation in solid-state system.

Multiwave mixing processes in the ultraslow propagating regime has been an area of active research for many years. This mainly due to the potentially wide range of applications in diverse fields as well as high-efficiency generation of coherent radiation, optical image amplification, quantum nonlinear optics, quantum information science, and so on. As one of the centerpieces of modern technology, how to realize efficiency generation of coherent light has been of primary importance. Harris and co-workers^{1,2} have introduced the idea of electromagnetically induced transparency (EIT)³, which allows controlled manipulations of the optical properties of atom or atom-like media and hence leads to suppression of linear absorption and enhancement of nonlinear susceptibility. This means that EIT-based high efficient four-wave mixing (FWM) process is hopefully possible to obtain by eliminating linear absorption. The FWM in EIT media has been the focus of several recent studies⁴⁻¹¹. Hemmer and coworkers introduced the double Λ -scheme as an important tool in EIT-based resonant FWM⁴. Deng *et.al.*^{5,6} suggested a novel channel opening technique of FWM in a four-level system and showed that nonexisting wave-mixing channels may be opened deeply inside the medium and the efficiency of the FWM can be significantly enhance. Subsequently, the efficient multiwave mixing resulted from multiphoton destructive interference⁸ and double-dark resonances⁹⁻¹¹ have been proposed. Experimentally, the results on FWM in a thermal vapor cell of rubidium atoms via highly excited Rydberg states has been presented¹².

FWM in atomic vapors has been explored extensively in the past. Much of the recent literature has exploited in semiconductor quantum wells (QWs) structure. QWs structure provides a potential energy well, the confined two dimension electron gas behaves atomlike optical responses. Different from atomic system, the advantages of semiconductor QWs structure such as large electric dipole momentums, controllable intersubband energies and the electron function symmetries create the opportunities of building opto-electron devices that harness atom physics. There is great interest in extending the study of quantum interference phenomena from atomic system to semiconductor QWs structure, and several quantum optical coherence and interference effects¹³⁻³⁰ have been studied theoretically and experimentally. For examples, EIT^{13,14}, ultrafast all-optical switching via Fano interference¹⁵, slow light^{16,17} and optical solitons via interband transitions²², tunneling-induced enhancement of Kerr nonlinearity^{24,25}, and so on. FWM processes in semiconductor QWs structure have also been paid much attention. The idea of resonant FWM in double Λ -scheme⁴ has been extended into asymmetric double QWs structure based on interband³¹ and intersubband transitions³², respectively. Subsequently, a cascade configuration for obtaining highly efficient FWM process in three coupled QWs based on intersubband transition was suggested³³. More recently, FWM in the diamond configuration in an atomic vapor³⁴ and X-ray/optical sum-frequency generation in diamond³⁵ have been demonstrated experimentally. FWM process in quantum dot (QD) nanostructure has been suggested theoretically³⁶.

In QWs structure, the resonant tunneling induces not only transparency, but also the enhancement of Kerr nonlinearity^{24,25}. Thus, the natural question is can we enhance the efficiency of FWM in QWs structure via resonant tunneling. In the present paper, we suggest an asymmetric double QWs structure and address this question. The basic idea is to combine the constructive interference in Kerr nonlinearity and EIT-based channel opening technique. Our studies demonstrate that with two continuous-wave (cw) laser fields and a weak, pulsed pump field, a pulsed FWM field can be generated. With the presence of resonant tunneling, the enhancement of conversion efficiency of FWM can be achieved. In particular, around the center frequency, the FWM conversion efficiency can be enhanced dramatically. This QWs structure may be useful to generate coherent long wavelength radiation in solid materials.

The asymmetric double QWs structure, which interacts with three laser fields, is shown in Fig. 1. This structure consists of a $\text{Al}_{0.04}\text{Ga}_{0.96}\text{As}$ layer (shallow well) with thickness of 11.0 nm and a 9.5 nm GaAs layer (deep well), and they are separated by a 3.8 nm $\text{Al}_{0.4}\text{Ga}_{0.6}\text{As}$ potential barrier. Both the left side of shallow well and the right side of deep well are $\text{Al}_{0.4}\text{Ga}_{0.6}\text{As}$ potential barriers. In this structure, $|1\rangle$ and $|2\rangle$ with energies 34.5 meV and 62.3 meV are, respectively, the ground subbands of the left shallow and the right deep wells. Two subbands $|3\rangle$ and $|4\rangle$ with eigenenergies 135.5 meV and 141.5 meV are created by mixing the first excited subbands of the shallow ($|se\rangle$) and deep ($|de\rangle$) wells by resonant tunneling. Their corresponding wave functions are symmetric and asymmetric combinations of $|se\rangle$ and $|de\rangle$, i.e., $|3\rangle = (|se\rangle - |de\rangle)/\sqrt{2}$ and $|4\rangle = (|se\rangle + |de\rangle)/\sqrt{2}$. $|5\rangle$ is the second excited subband of the right

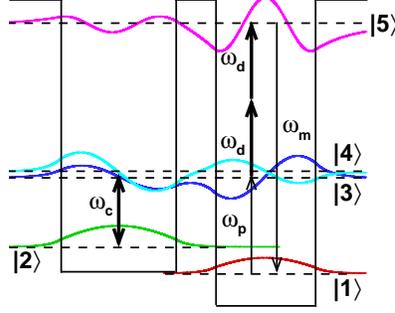


FIG. 1: (color online) Conduction subband of the asymmetric double quantum wells (QWs) structure, in which two ground subbands $|1\rangle$ and $|2\rangle$ are, respectively, driven by a weak pulsed pump and a continuous-wave control fields via the subbands $|3\rangle$ and $|4\rangle$. The subbands $|3\rangle$ and $|3\rangle$ are coupled with $|5\rangle$ by a two-photon process. The solid curves represent the corresponding wave functions.

deep well, and its energy is 296.3 meV. A weak pulsed pump (ω_p) and a continuous wave (ω_c) fields, respectively, couple the ground subbands $|1\rangle$ and $|2\rangle$ via two short-lived subbands $|3\rangle$ and $|4\rangle$. Subbands $|1\rangle$, $|3\rangle$, and $|4\rangle$ form the usual TIT scheme together with the pump field. The driven field (ω_d) provides a two-photon coupling to the FWM subband $|5\rangle$, which is dipole coupled to the ground subband $|1\rangle$. The pump field and the resonant two-photon field induce the FWM processes $|1\rangle \rightarrow |3\rangle \rightarrow |5\rangle \rightarrow |1\rangle$ and $|1\rangle \rightarrow |4\rangle \rightarrow |5\rangle \rightarrow |1\rangle$, then generate a coherent radiation field at frequency ω_m with $\omega_m = \omega_p + 2\omega_d$. The solid curves represent the corresponding wave functions. Without the subband $|4\rangle$, the scheme is simplified as that in Ref.⁵. The novelty of this scheme under consideration is that it combines the advantages of the Deng-scheme⁵ and constructive interference associated with Kerr nonlinearity induced by resonant tunneling^{24,25}. The band structure is designed with large electronic dipole momentum μ_{15} , which can enhance the FWM efficiency.

Under the dipole and rotating-wave approximations (RWA), the structure dynamics can be described using equations of motion for probability amplitudes $b_i(t)$ ($i = 1 - 5$) of the states

$$i\partial_t b_1 + \Omega_p b_3 + m\Omega_p b_4 + \Omega_m b_5 = 0, \quad (1)$$

$$(i\partial_t + d_2)b_2 + \Omega_c b_3 + q\Omega_c b_4 = 0, \quad (2)$$

$$(i\partial_t + d_3)b_3 + \Omega_p b_1 + \Omega_c b_2 + \Omega_d^{(2)} e^{-i\Delta k z} b_5 = 0, \quad (3)$$

$$(i\partial_t + d_4)b_4 + m\Omega_p b_1 + q\Omega_c b_2 + k\Omega_d^{(2)} e^{-i\Delta k z} b_5 = 0, \quad (4)$$

$$(i\partial_t + d_5)b_5 + \Omega_m b_1 + \Omega_d^{(2)} e^{i\Delta k z} (b_2 + k b_5) = 0. \quad (5)$$

As usual, $\Omega_p = \mu_{31}E_p/2\hbar$, $\Omega_c = \mu_{32}E_c/2\hbar$, and $\Omega_m = \mu_{51}E_m/2\hbar$ are, one half of the Rabi frequencies for the respectively transitions with μ_{31} , μ_{32} , μ_{51} being corresponding dipole matrix elements, and $\Omega_d^{(2)}$ is the direct two-photon Rabi frequency from subband $|3\rangle$ to $|5\rangle$. $m = \mu_{41}/\mu_{31}$, $q = \mu_{42}/\mu_{32}$, and $k = \mu_{54}/\mu_{53}$ give the ratios between the relevant subband transition dipole momentum. In the QWs structure under consideration, it can be calculated that $m = -0.42$, $q = 1.63$, and $k = -1.12$. $d_2 = \Delta_p - \Delta_c + i\gamma_2$, $d_3 = \Delta_p + i\gamma_3$, $d_4 = \Delta_p - \delta + i\gamma_4$, and $d_5 = \Delta_m + i\gamma_5$ with $\Delta_{p(c,m)} = \omega_{p(c,m)} - (\omega_{3(3,5)} - \omega_{1(2,1)})$ being detunings, and γ_j ($j = 2$ to 5) being the electron decay rate of the state $|j\rangle$. In a usual way, $\Delta k = k_p + 2k_d - k_m$ denotes phase mismatching. In order to correctly predict the efficiency of FWM field generated, equations (1)-(5) must be solved together with the wave equations for the pump and FWM fields. Under the slowly varying envelop approximation, they read

$$\frac{\partial \Omega_p(z, t)}{\partial z} + \frac{1}{c} \frac{\partial \Omega_p(z, t)}{\partial t} = i\kappa_p (b_3 + m b_4) b_1^*, \quad (6)$$

$$\frac{\partial \Omega_m(z, t)}{\partial z} + \frac{1}{c} \frac{\partial \Omega_m(z, t)}{\partial t} = i\kappa_m b_5 b_1^*. \quad (7)$$

Here, the propagation constant $\kappa_{p(m)} = N\omega_{p(m)}|\mu_{31(51)}|^2/(\hbar\epsilon_0 c)$, with N being the electron concentration, and c the speed of light in vacuum. In the following, we assume Ω_p and the two-photon transition field $\Omega_d^{(2)}$ are very

comparatively weak (i.e., considering the FWM process at low pump intensity), the electronic ground subband $|1\rangle$ is not depleted, i.e., $b_1 \approx 1$. Under these assumptions, following the standard processes⁵, one immediately has, in dimensionless form,

$$\alpha_3 + m\alpha_4 = -\frac{W_p\tau D_p}{D}, \quad (8)$$

$$\alpha_5 = -\frac{W_m\tau}{\eta + d_5\tau} + \frac{W_p\tau\Omega_d^{(2)}\tau e^{i\Delta kz} D_m}{(\eta + d_5\tau)D}, \quad (9)$$

in which α_j ($j = 3 - 5$), W_p and W_m are the Fourier transforms of b_j , Ω_p , and Ω_m . $\eta = \omega\tau$ is the dimensionless Fourier transform variable. D , D_p , and D_m are, respectively, given by

$$\begin{aligned} D &= (\eta + d_2\tau)(\eta + d_3\tau)(\eta + d_4\tau) - [(\eta + d_4\tau) + q^2(\eta + d_3\tau)](\Omega_c\tau)^2, \\ D_p &= (\eta + d_2\tau)[(\eta + d_4\tau) + m^2(\eta + d_3\tau)] - (q - m)^2(\Omega_c\tau)^2, \\ D_m &= (\eta + d_2\tau)[(\eta + d_4\tau) + mk(\eta + d_3\tau)] - (q - k)(q - m)(\Omega_c\tau)^2. \end{aligned}$$

Taking Fourier transform of Eqs. (6)-(7), and combining the results of (8) and (9), we obtain

$$W_m(z, \eta) = \frac{\kappa_m c\tau^2 \Omega_d^{(2)} \tau D_m W_p(0, \eta)}{(\eta + d_5\tau)D} \frac{e^{iBz/c\tau} - 1}{B} \exp \left\{ \frac{i\eta z}{c\tau} \left[1 - \frac{\kappa_m c\tau^2}{\eta(\eta + d_5\tau)} \right] \right\}. \quad (10)$$

Here, $W_p(0, \eta)$ is the Fourier transform of $\Omega_p(z, t)$ at the entrance of the QWs structure, and B is given by

$$B = \Delta k\tau + \kappa_m c\tau^2 / (\eta + d_5\tau) - \kappa_p c\tau^2 D_p / D.$$

For the FWM emission process, the boundary condition $W_m(0, \eta) = 0$ is applied. Equation (10) is the main result of the present paper, it gives the generated FWM field $W_m(z, \eta)$ at arbitrary frequency detunings. The expression of $D_{p(m)}$ exhibits the role of resonant tunneling clearly. In the QWs structure suggested, resonant tunneling leads to the asymmetric and symmetric wave functions of subbands $|3\rangle$ and $|4\rangle$. As a result, we have $q \cdot m < 0$ and $q \cdot k < 0$, which indicate that resonant tunneling can modify the optical nonlinearity such as enhancement of FWM conversion efficiency [see Eq. (10) together with D_p and D_m]. By taking $q = k = m = 0$, the subband $|4\rangle$ is decoupled, the scheme is therefore reduced to Deng-scheme⁵. It can be easily checked that Eq. (10) reduces to the main result of Ref.⁵. The generated FWM power can be calculated by taking inversion Fourier transform of Eq. (10). We assume the pump field at the entrance of the QWs structure has the form⁵

$$W_p(0, \eta) = \frac{\tau\Omega_p(0, 0)}{\sqrt{2}} e^{-\eta^2/4}, \quad (11)$$

and define the conversion efficiency of FWM ρ as^{5,9}

$$\rho = \left| \frac{\mu_{31} W_m(z, \eta)}{\mu_{51} \tau \Omega_d^{(2)} \tau \Omega_p(0, 0) / \sqrt{2}} \right|^2. \quad (12)$$

In Figs. 2(a)-(f), we plot the conversion efficiency ρ as a function of η with different propagation distance (corresponding to different optical depth). The parameters are chosen as $N = 10^{23} \text{ m}^{-3}$, $\gamma_3 = \gamma_4 \approx 1.0 \text{ meV}$, $\gamma_5 \approx 0.1 \text{ meV}$, $\Delta_p = 0.5 \text{ meV}$, $\Delta_c = 3.0 \text{ meV}$, $\Omega_c = 2.0 \text{ meV}$. As discussed in Ref.⁵, a phase-matched FWM field can be produced if the reduced group velocity of the pump wave ω_p subject to EIT is about equal to the group velocity of the generated FWM wave ω_m . The detuning of the generated FWM field is therefore taken as $\Delta_m = 72.5 \text{ } \mu\text{eV}$ [Figs. 2(a)-(c)] and $\Delta_m = -72.5 \text{ } \mu\text{eV}$ [Figs. 2(d)-(f)]. With these parameters, the group velocities of the pump and FWM waves are matched ($v_g^p \approx v_g^s \approx 3.7 \times 10^{-3} c$), which enhances the field-medium interaction time and also results to an increase of the FWM conversion efficiency of the system. For a quantitative comparison with Ref.⁵ that treated the EIT-enhanced FWM process, we have also plot the evolutions of ρ versus η in the case of no resonant tunneling (i.e., taking $q = k = m = 0$ such that the subband $|4\rangle$ is decoupled). The result is shown by the dashed curves in Figs. 2(a)-(f). We see that, by virtue of resonant tunneling, the conversion efficiency is enhanced dramatically, especially for small propagation distance. For examples, with $z = 1.0 \text{ } \mu\text{m}$ and $z = 10.0 \text{ } \mu\text{m}$, the conversion efficiency can be enhanced more than one order of magnitude around the center frequency [see Figs. 2(a), (b), (d), and (e)]. Notice that, with increasing the propagation distance, the behaviors of conversion efficiency with and without resonant tunneling are totally different. Equation (10) indicates that there are two generated waves with the same ultraslow

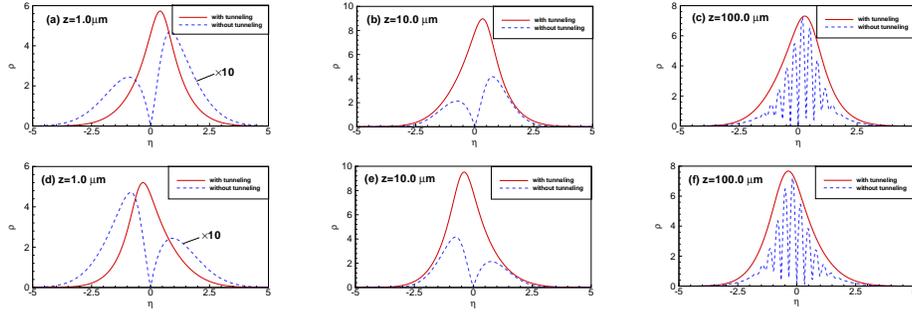


FIG. 2: (color online) The conversion efficiency of FWM ρ as a function of η with and without resonant tunneling. The values of Δ_m corresponding to the first and second ranks are, respectively, $\Delta_m = -27.5 \mu\text{eV}$ and $\Delta_m = 27.5 \mu\text{eV}$. The other parameters are explained in the text.

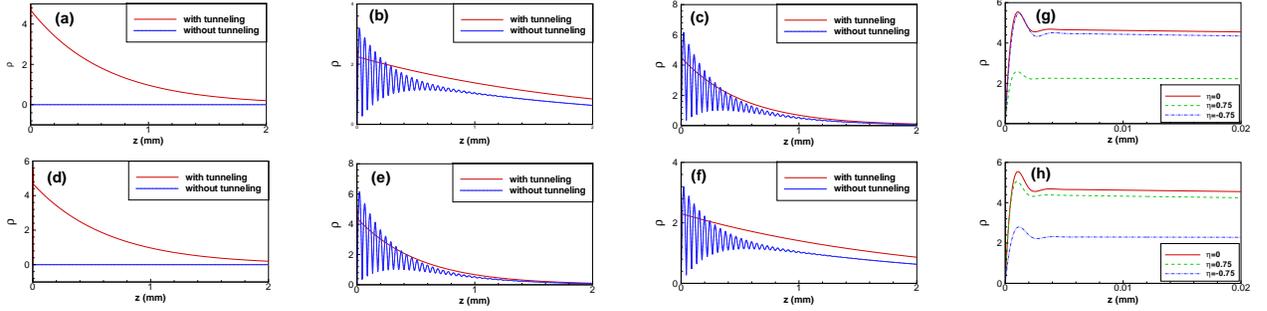


FIG. 3: (color online) The conversion efficiency of FWM ρ as a function of propagation distance z with and without resonant tunneling. The value of Δ_m corresponding to the first and second ranks are taken as $\Delta_m = 72.5 \mu\text{eV}$ and $\Delta_m = -72.5 \mu\text{eV}$. The other parameters are explained in the text.

group velocity when phase matching is achieved. In the case of without resonant tunneling, the interference between two waves leads to oscillation [shown in Figs. 2(c) and (f) with dashed curves]. Direct comparison of these result implies that the enhancement of FWM conversion efficiency can be achieved by combining resonant tunneling-induced constructive interference in Kerr nonlinearity and EIT. In the regime where the propagation distance is small, the conversion efficiency of FWM can be enhanced more than one order of magnitude than that without resonant tunneling in the vicinity of center frequency.

In order to understand the influence of resonant tunneling on the FWM process more clearly, we plot, in Fourier space, the FWM conversion efficiency ρ with different values of η as a function of propagation distance z in Figs. 3(a)-(f) for two set of parameters. The value of Δ_m has been taken as $\Delta_m = 72.5 \mu\text{eV}$ and $\Delta_m = -72.5 \mu\text{eV}$ in the left and right columns. The other parameters are same as those in Figs. 2. In the plot we took $\eta = \pm 0.75$ which corresponds to the location of the FWM peaks at $z = 10.0 \mu\text{m}$ without resonant tunneling (see Figs. 2). The FWM conversion efficiency with resonant tunneling can be larger than that without resonant tunneling, especially in the region near the center frequency. As those illustrated in Refs.^{24,25}, the physical reason behind is the constructive interference to Kerr nonlinearity induced by resonant tunneling [please see Eq. (10)]. As the propagation distance increases, owing to resonant tunneling, ρ increases rapidly, and the details in very small propagation distance region have been shown in Figs. 3(g) and (h). Deep inside the medium, the effective interference limits the further production of the FWM field. When the generated FWM wave becomes sufficiently intense, excitation channels $|1\rangle \rightarrow |3\rangle$ and $|1\rangle \rightarrow |4\rangle$ via $\Omega_m + 2\Omega_d^*$ open and become important. Consequently, this efficient backcoupling pathway results to competitive multiphoton excitations of the FWM generating state⁸.

To demonstrate the role of the control field, we plot the FWM conversion efficiency ρ versus η without the control field in Figs. 4(a) and (b). At certain pump detuning ($\Delta_p = 4.0 \text{ meV}$), the tunneling-induced destructive interference between transition channels $|3\rangle \rightarrow |1\rangle$ and $|4\rangle \rightarrow |1\rangle$ leads to the negligible small absorption, i.e., TIT, which opens the channel for FWM process. The physics behind is basically the same as EIT illustrated in Refs.^{5,8}. We choose the detuning of the FWM wave as $\Delta_m = -74.5 \mu\text{eV}$ in Fig. 4(a) and $\Delta_m = 74.5 \mu\text{eV}$ in Fig. 4(b) such that the group velocities of the pump and generated FWM waves are matched ($v_g^p \approx v_g^m \approx 1.5 \times 10^{-2}c$). The results with three different propagation distances are plotted. Direct comparison of Figs. 4 with the corresponding results shown

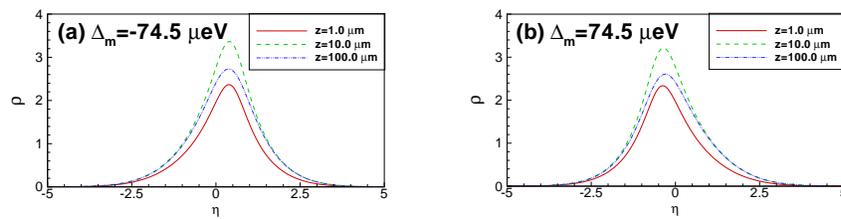


FIG. 4: (color online) The conversion efficiency of FWM ρ versus η without the control field Ω_c .

in Figs. 2), we can conclude that the presence of the control field modifies the linear optical property of the QWs structure, as well as the FWM process. As results, the matched reduced group velocity ensures larger interaction time and also leads to an increase of the FWM conversion efficiency.

In conclusion, we have suggested an asymmetric double QWs structure to achieve parameter generation of a new laser radiation with high conversion efficiency. This structure combines resonant tunneling together with the advantages of EIT-enhanced FWM scheme. By virtue of the constrictive interference in Kerr nonlinearity induced by resonant tunneling, high efficiency of FWM process can be achieved. Especially for small propagation distance and around the center frequency, the FWM conversion efficiency can be enhanced more than one order of magnitude than that without resonant tunneling. Recalling the flexible design of QWs structure and the fact that the resonant tunneling can be controlled by applying a bias voltage, we believe that this excellent performance offers the possibility of developing practical and portable electrooptically modulated devices based on FWM at low pump intensity.

We thank the financial support from the NSF-China under Grant No. 11104176, the NSF of Shaanxi Province under Grant No. 2011JQ1008, the Fundamental Research Funds for the Central University under Grant No. GK201003003, as well as the Open Fund from the SKLPS of ECNU. S.L.F would like to acknowledge the support of NSF-China under Grant No. 11104174.

* fanshuangli@snnu.edu.cn

† sqgong@ecust.edu.cn

- ¹ S. E. Harris, J. E. Field, and A. Imamoglu, Phys. Rev. Lett. **64**, 1107 (1990).
- ² S. E. Harris and L. V. Hau, Phys. Rev. Lett. **82**, 4611 (1999).
- ³ M. Fleischhauer, A. Imamoglu, and J. P. Marangos, Rev. Mod. Phys. **77**, 633 (2005).
- ⁴ P. R. Hemmer, D. P. Katz, J. Donoghue, M. Cronin-Golomb, M. S. Shahriar, and P. Kumar, Opt. Lett. **20**, 982 (1995).
- ⁵ L. Deng, M. Kozuma, E. W. Hagley, and M. G. Payne, Phys. Rev. Lett. **88**, 143902 (2002); *ibid.* **93**, 129402 (2004).
- ⁶ L. Deng and M. G. Payne, Phys. Rev. A **68**, 051801(R) (2003).
- ⁷ Ying Wu, M. G. Payne, E. W. Hagley, and L. Deng, Opt. Lett. **29**, 2294 (2004).
- ⁸ Ying Wu and Xiaoxue Yang, Phys. Rev. A **70**, 053818 (2004).
- ⁹ Yueping Niu, Ruxin Li, and Shangqing Gong, Phys. Rev. A **71**, 043819 (2005).
- ¹⁰ Weifeng Yang, Shangqing Gong, Yueping Niu, Shiqi Jin, and Zhizhan Xu, J. Phys. B **38**, 2657 (2005).
- ¹¹ Hui-jun Li and Guoxiang Huang, Phys. Rev. A **76**, 043809 (2007).
- ¹² A. Kölle, G. Epple, H. Kübler, R. Löw, and T. Pfau, Phys. Rev. A **85**, 063821 (2012).
- ¹³ M. C. Phillips and H. Wang, Phys. Rev. Lett. **91**, 183602 (2003).
- ¹⁴ A. Joshi, Phys. Rev. B **79**, 115315 (2009).
- ¹⁵ J. H. Wu, J. Y. Gao, J. H. Xu, L. Silvestri, M. Artoni, G. C. La Rocca, and F. Bassani, Phys. Rev. Lett. **95**, 057401 (2005).
- ¹⁶ Chunhua Yuan and K. D. Zhu, Appl. Phys. Lett. **89**, 052113 (2006).
- ¹⁷ P. Ginzburg and M. Orenstein, *oe***14**, 12467 (2006).
- ¹⁸ E. Paspalakis, M. Tsaousidou, and A. F. Terzis, Phys. Rev. B **73**, 125344 (2006).
- ¹⁹ E. Paspalakis, Z. Kis, E. Voutsinas, and A. F. Terzis, Phys. Rev. B **69**, 155316 (2004).
- ²⁰ E. Paspalakis, A. Kalini, and A. F. Terzis, Phys. Rev. B **73**, 073305 (2006).
- ²¹ Jin-Hui Wu, Jin-Yue Gao, Ji-Hua Xu, L. Silvestri, M. Artoni, G. C. La Rocca, and F. Bassani, Phys. Rev. A **73**, 053818 (2006).
- ²² Chengjie Zhu and Guoxiang Huang, Phys. Rev. B **80**, 235408 (2009).
- ²³ Wen-Xing Yang, Jing-Min Hou, and Ray-Kuang Lee, Phys. Rev. A **77**, 033838 (2008).
- ²⁴ Hui Sun, Yueping Niu, Ruxin Li, Shiqi Jin, and Shangqing Gong, Opt. Lett. **32**, 2475 (2007).
- ²⁵ H. Sun, S. L. Fan, X. L. Feng, C. F. Wu, S. Q. Gong, G. X. Huang, and C. H. Oh, Opt. Express **20**, 8485 (2012).
- ²⁶ S. G. Kosionis, A. F. Terzis, and E. Paspalakis, J. Appl. Phys. **109**, 084312 (2011).
- ²⁷ Hui Sun, Shangqing Gong, Yueping Niu, Shiqi Jin, Ruxin Li, and Zhizhan Xu, Phys. Rev. B **74**, 155314 (2006).

- ²⁸ Hui Sun, Xun-Li Feng, Shangqing Gong, and C. H. Oh, Phys. Rev. B **79**, 193404 (2009).
- ²⁹ Hui Sun, Xun-Li Feng, Chunfeng Wu, Jin-Ming Liu, Shangqing Gong, and C. H. Oh, Phys. Rev. B **80**, 235404 (2009).
- ³⁰ Chengjie Zhu and Guoxiang Huang, Opt. Express **19**, 23364 (2011).
- ³¹ Xiangying Hao, Jiahua Li, Jibing Liu, Peijun Song, and Xiaoxue Yang, Phys. Lett. A **372**, 2509 (2008).
- ³² Wen-Xing Yang, Jing-Min Hou, and Ray-Kuang Lee, J. Mod. Opt. **56**, 716 (2009).
- ³³ Xiangying Hao, Jiahua Li, and Xiaoxue Yang, Opt. Commun. **282**, 3339 (2009).
- ³⁴ R. T. Willis, F. E. Becerra, L. A. Orozco, and S. L. Rolston, Phys. Rev. A **79**, 033814 (2009).
- ³⁵ T. E. Glover, D. M. Fritz, M. Cammarata, T. K. Allison, Sinisa Coh, J. M. Feldkamp, H. Lemke, D. Zhu, Y. Feng, R. N. Coffee, M. Fuchs, S. Ghimire, J. Chen, S. Shwartz, D. A. Reis, S. E. Harris, and J. B. Hastings, Nature **488**, 603 (2012).
- ³⁶ Xiangying Hao, Jing Wu, and Ying Wang, J. Opt. Soc. Am. B **29**, 420 (2012).